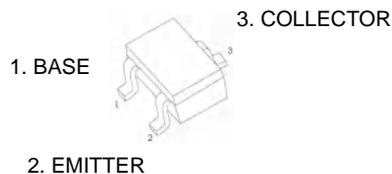




### MMBT3906T TRANSISTOR (PNP)

#### FEATURES

- Epitaxial Planar Die Construction
- Complementary NPN Type Available
- Also Available in Lead Free Version



MARKING:3N

SOT-523

#### MAXIMUM RATINGS ( $T_a=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol          | Parameter                               | Value   | Units                       |
|-----------------|---|---------|-----------------------------|
| $V_{CBO}$       | Collector-Base Voltage                  | -40     | V                           |
| $V_{CEO}$       | Collector-Emitter Voltage               | -40     | V                           |
| $V_{EBO}$       | Emitter-Base Voltage                    | -5.0    | V                           |
| $I_C$           | Collector Current -Continuous           | -200    | mA                          |
| $P_C$           | Collector Power Dissipation             | 150     | mW                          |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 833     | $^{\circ}\text{C}/\text{W}$ |
| $T_J$           | Operating Temperature                   | 150     | $^{\circ}\text{C}$          |
| $T_{stg}$       | Storage Temperature                     | -55-150 | $^{\circ}\text{C}$          |

#### ELECTRICAL CHARACTERISTICS( $T_a=25^{\circ}\text{C}$ unless otherwise specified)

| Parameter                            | Symbol         | Test conditions   | Min   | Typ | Max   | Unit          |
|--------------------------------------|----------------|---|-------|-----|-------|---------------|
| Collector-base breakdown voltage     | $V_{(BR)CBO}$  | $I_C=-10\mu\text{A}, I_E=0$                                   | -40   |     |       | V             |
| Collector-emitter breakdown voltage  | $V_{(BR)CEO}$  | $I_C=-1\text{mA}, I_B=0$                                      | -40   |     |       | V             |
| Emitter-base breakdown voltage       | $V_{(BR)EBO}$  | $I_E=-10\mu\text{A}, I_C=0$                                   | -5    |     |       | V             |
| Collector cut-off current            | $I_{CBO}$      | $V_{CB}=-30\text{V}, I_E=0$                                   |       |     | -0.1  | $\mu\text{A}$ |
| Emitter cut-off current              | $I_{EBO}$      | $V_{EB}=-5\text{V}, I_C=0$                                    |       |     | -0.1  | $\mu\text{A}$ |
| DC current gain                      | $h_{FE(1)}$    | $V_{CE}=-1\text{V}, I_C=-0.1\text{mA}$                        | 60    |     |       |               |
|                                      | $h_{FE(2)}$    | $V_{CE}=-1\text{V}, I_C=-1\text{mA}$                          | 80    |     |       |               |
|                                      | $h_{FE(3)}$    | $V_{CE}=-1\text{V}, I_C=-10\text{mA}$                         | 100   |     | 300   |               |
|                                      | $h_{FE(4)}$    | $V_{CE}=-1\text{V}, I_C=-50\text{mA}$                         | 60    |     |       |               |
|                                      | $h_{FE(5)}$    | $V_{CE}=-1\text{V}, I_C=-100\text{mA}$                        | 30    |     |       |               |
| Collector-emitter saturation voltage | $V_{CE(sat)1}$ | $I_C=-10\text{mA}, I_B=-1\text{mA}$                           |       |     | -0.25 | V             |
|                                      | $V_{CE(sat)2}$ | $I_C=-50\text{mA}, I_B=-5\text{mA}$                           |       |     | -0.4  | V             |
| Base-emitter saturation voltage      | $V_{BE(sat)1}$ | $I_C=-10\text{mA}, I_B=-1\text{mA}$                           | -0.65 |     | -0.85 | V             |
|                                      | $V_{BE(sat)2}$ | $I_C=-50\text{mA}, I_B=-5\text{mA}$                           |       |     | -0.95 | V             |
| Transition frequency                 | $f_T$          | $V_{CE}=-20\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$       | 250   |     |       | MHz           |
| Collector output capacitance         | $C_{obo}$      | $V_{CB}=-5\text{V}, I_E=0, f=1\text{MHz}$                     |       |     | 4.5   | pF            |
| Input capacitance                    | $C_{iob}$      | $V_{EB}=-0.5\text{V}, I_E=0, f=1\text{MHz}$                   |       |     | 10    | pF            |
| Noise figure                         | NF             | $V_{CE}=-5\text{V}, I_C=0.1\text{mA}$ ,                       |       |     | 4     | dB            |
| Delay time                           | $t_d$          | $f_{\Omega}$<br>$V_{CC}=-3\text{V}, V_{BE(OFF)}=-0.5\text{V}$ |       |     | 35    | ns            |
| Rise time                            | $t_r$          | $I_C=-10\text{mA}, I_B=-1\text{mA}$                           |       |     | 35    | ns            |
| Storage time                         | $t_s$          | $V_{CC}=-3\text{V}, I_C=-10\text{mA}$                         |       |     | 225   | ns            |
| Fall time                            | $t_f$          | $I_{B1}=I_{B2}=-1\text{mA}$                                   |       |     | 75    | ns            |

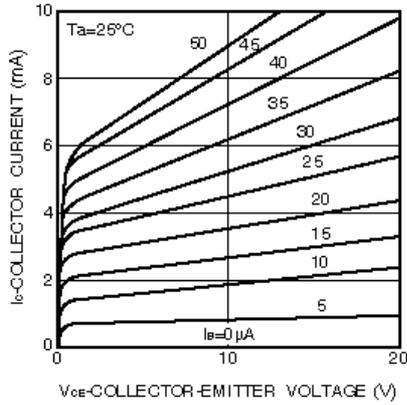


Fig.1 Grounded emitter output characteristics

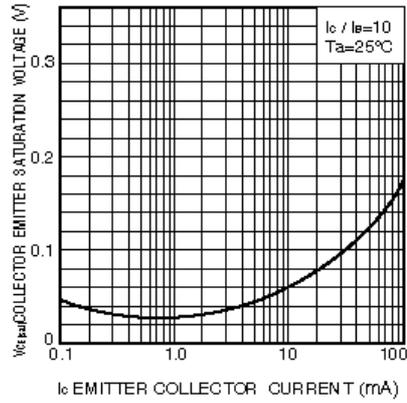


Fig.2 Collector-emitter saturation voltage vs. collector current

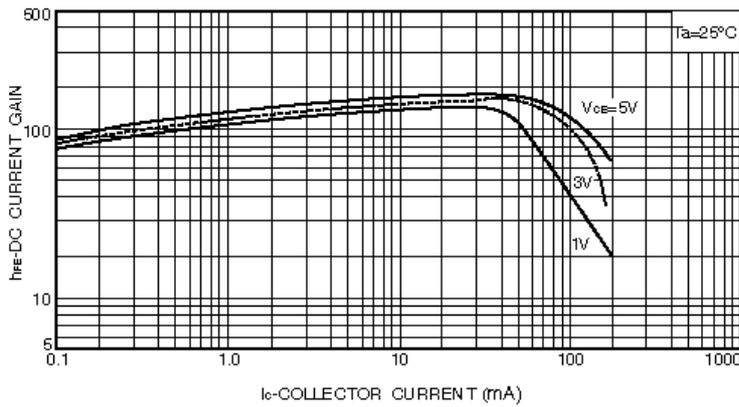


Fig.3 DC current gain vs. collector current ( I )

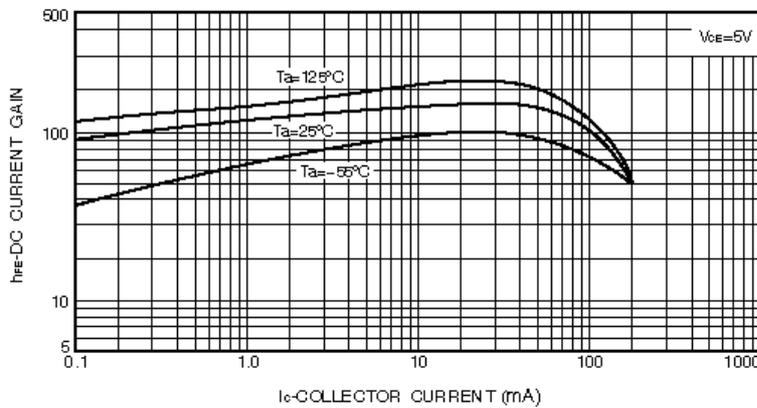


Fig.4 DC current gain vs. collector current ( II )

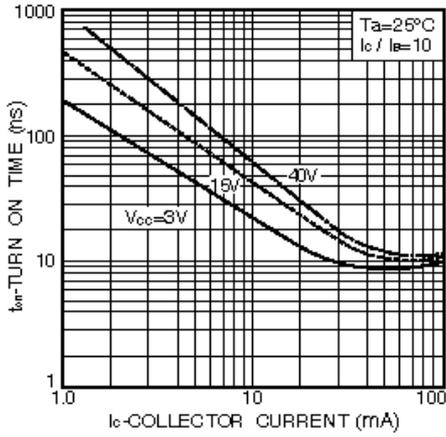


Fig.8 Turn-on time vs. collector current

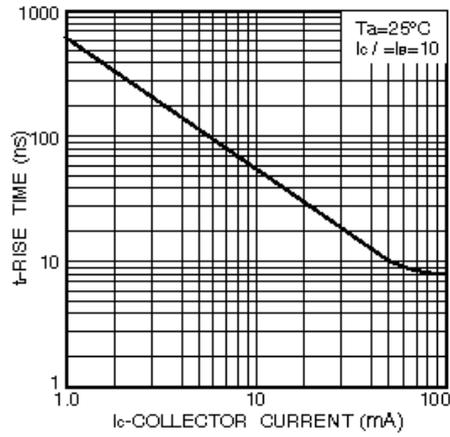


Fig.9 Rise time vs. collector current

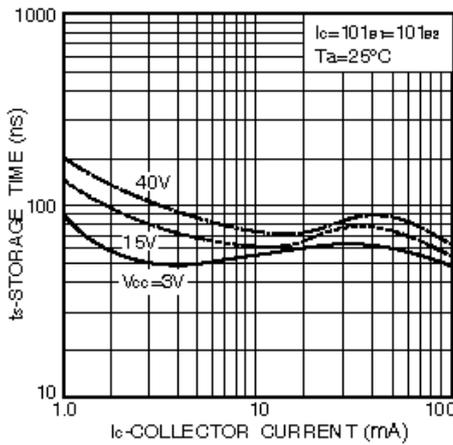


Fig.10 Storage time vs. collector current

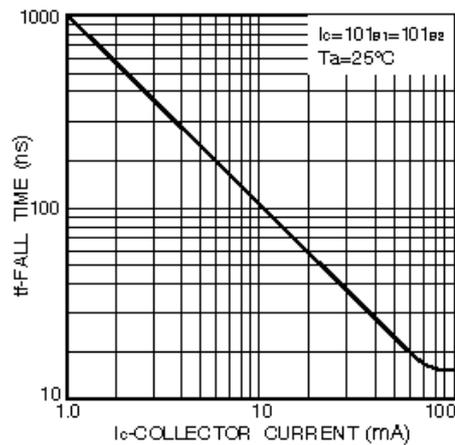


Fig.11 Fall time vs. collector current

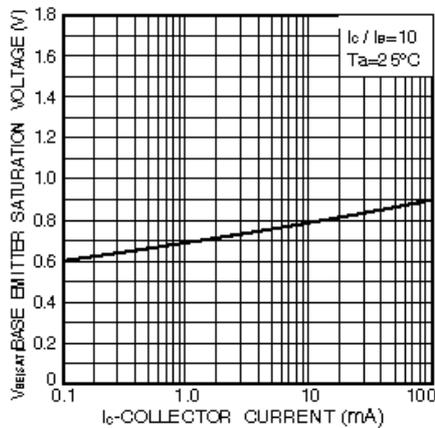


Fig.6 Base-emitter saturation voltage vs. collector current

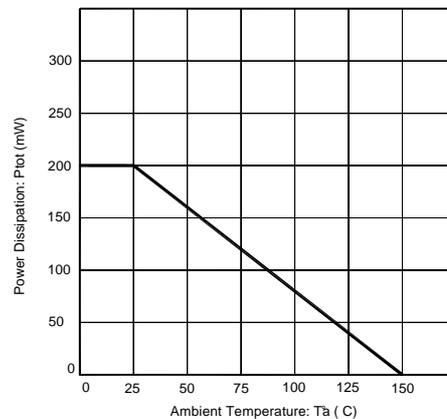
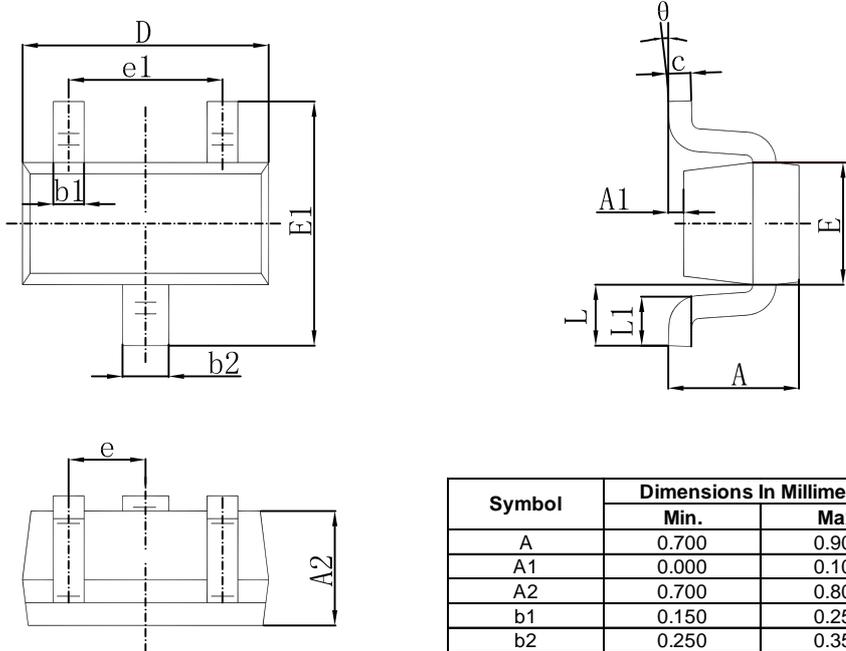


Fig.10 Power Dissipation vs Ambient Temperature

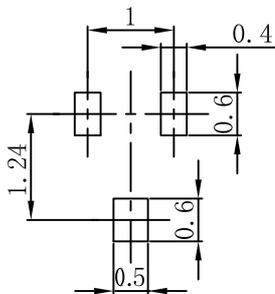


### SOT-523 Package Outline Dimensions



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min.                      | Max.  | Min.                 | Max.  |
| A      | 0.700                     | 0.900 | 0.028                | 0.035 |
| A1     | 0.000                     | 0.100 | 0.000                | 0.004 |
| A2     | 0.700                     | 0.800 | 0.028                | 0.031 |
| b1     | 0.150                     | 0.250 | 0.006                | 0.010 |
| b2     | 0.250                     | 0.350 | 0.010                | 0.014 |
| c      | 0.100                     | 0.200 | 0.004                | 0.008 |
| D      | 1.500                     | 1.700 | 0.059                | 0.067 |
| E      | 0.700                     | 0.900 | 0.028                | 0.035 |
| E1     | 1.450                     | 1.750 | 0.057                | 0.069 |
| e      | 0.500 TYP.                |       | 0.020 TYP.           |       |
| e1     | 0.900                     | 1.100 | 0.035                | 0.043 |
| L      | 0.400 REF.                |       | 0.016 REF.           |       |
| L1     | 0.260                     | 0.460 | 0.010                | 0.018 |
| θ      | 0°                        | 8°    | 0°                   | 8°    |

### SOT-523 Suggested Pad Layout



- Note:
1. Controlling dimension: in millimeters.
  2. General tolerance:  $\pm 0.05\text{mm}$ .
  3. The pad layout is for reference purposes only.